

# **Low-Current Superhet Remote-Control Receiver**

### **Description**

The U4313B is a monolithic integrated circuit in bipolar technology for low-current UHF remote-control superheterodyne receivers in amplitude- or frequency-modulated mode. Typical applications are keyless car

lock-, alarm- or tele-control remote indication systems. Especially for automotive applications, it supports a superhet design with less than 1 mA total current consumption, as required by the car manufacturers.

#### **Features**

- Usable for amplitude- and frequency-modulated transmission systems
- Extremely low quiescent current (approximately 1 mA in standby mode due to wake-up concept)
- Wide power supply voltage range (3 to 13 V)
- Sensitive IF amplifier for 10.7-MHz operating frequency
- Logarithmic AM demodulator
- FM demodulator
- Monoflop exit to wake up a microcontroller
- High-performance operational amplifier to realize a data recovering filter
- Inverting clamping comparator with amplitudedepending hysteresis for data regeneration

## **Block Diagram**

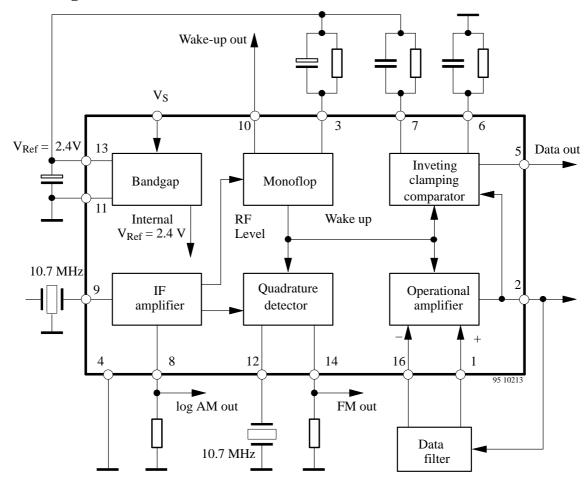
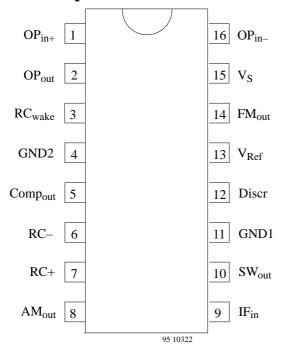


Figure 1. Block diagram



Function

# **Pin Description**



1	$OP_{in+}$	OP amplifier non-inverted input	
2	OP <sub>out</sub>	OP amplifier output	
3	RC <sub>wake</sub>	RC wake-up reset time	
4	GND2	Ground of the logical circuits	
5	Compout	Inverting comparator output	
6	RC-	Comparator time constant	
7	RC+	Comparator time constant	
8	$AM_{out}$	AM current output	
9	IF <sub>in</sub>	IF input	
10	SW <sub>out</sub>	Wake-up output	
11	GND1	Ground of the analog circuits	
12	Discr	FM discriminator tank	
13	$V_{Ref}$	Reference voltage	
14	FM <sub>out</sub>	FM discriminator output	
15	$V_{S}$	Supply voltage	
16	OP <sub>in</sub> –	OP amplifier inverted input	

Internal connections see figures 4 to 19

Symbol

Figure 2. Pin description

# **Absolute Maximum Ratings**

Parameters	Symbol	Value	Unit
Supply voltage	$V_{S}$	13	V
Power dissipation $T_{amb} = 85^{\circ}C$	P <sub>tot</sub>	400	mW
Junction temperature	$T_{j}$	125	°C
Ambient temperature	T <sub>amb</sub>	-40 to +85	°C
Storage temperature	T <sub>stg</sub>	-55 to +125	°C

## **Thermal Resistance**

Parameters		Symbol	Value	Unit
Junction ambient	DIP16	R <sub>thJA</sub>	120	K/W
	SO16L	$R_{thJA}$	100	K/W



## **Electrical Characteristics**

 $V_S = 5 \text{ V}, T_{amb} = 25 ^{\circ}\text{C}, \ f_{in} = 10.7 \text{ MHz}; \ \text{FM part:} \ f_{mod} = 1 \text{ kHz}, \ f_{dev} = 22.5 \text{ kHz}; \ \text{AM part:}, \ f_{mod} = 1 \text{ kHz}, \ m = 100\% \text{ unless otherwise specified}$ 

Parameters	Test Conditions / Pins	Symbol	Min.	Тур.	Max.	Unit
Characteristics	91					
Supply-voltage range	Pin 15	$V_{S}$	3		12	V
Quiescent supply current	Pin 15	Iq		1	1.3	mA
Active supply current	Pin 15	I <sub>act</sub>		2.8	3.6	mA
Bandgap		•				
Regulated voltage	Pin 13	V <sub>ref</sub>	2.3	2.4	2.5	V
Output current	Pin 13	I <sub>ref</sub>			5	mA
Source resistance	Pin 13	R <sub>Ref</sub>		2.3	5	Ω
External capacitor	Pin 13	C <sub>ref</sub>	10			μF
Power-supply suppression	f = 50 Hz Pin 13	psrr		60		dB
IF amplifier						•
Input resistance	Pin 9	Rin	180	330	520	Ω
Input capacitance	Pin 9	Cin		5		pF
Typical internal 3 dB	IF level 70 dBμV	f <sub>3dB</sub>	8		12	MHz
frequency	Pins 9 and 14					
-3 dB limiting point	Pin 9	V <sub>FM3dB</sub>		30		dBμV
Recovered data voltage	Pin 14	V <sub>FMout</sub>	50	130	230	mV
FM detector output	Pin 14	R <sub>FMout</sub>		50		kΩ
resistance						
AM rejection ratio	m = 30% Pins 9 and 14	AM <sub>rr</sub>		25		dB
Maximum AM input	Pin 9	V <sub>AMmax</sub>		90		dΒμV
voltage						
AM quiescent current	Pin 8	I <sub>AMout</sub>	10	22	37	μΑ
Maximum AM current	Pin 8	I <sub>AMoutmax</sub>		100		μΑ
Operational amplifier		1				1
Gain bandwidth product	Pins 1, 2 and 16	f <sub>t</sub>	3	4	6.5	MHz
Excess phase	Pins 1, 2 and 16	δ		80		degree
Open-loop gain	Pins 1, 2 and 16	g <sub>0</sub>	50	70	95	dB
Output-voltage range	Pin 2	$\Delta V_{\rm out}$		1.55		V
Common-mode input voltage	Pins 1 and 16	V <sub>in</sub>	0.7		1.7	V
Input offset voltage	Pins 1 and 16	Vos	-2.5	0	+2.5	mV
Maximum output current	Pin 2	I <sub>out</sub>			5	mA
Common-mode rejection	Pins 1 and 16	cmrr	65	85		dB
ratio						
Total harmonic distortion	$V_{in}$ < 300 mV, f = 33 kHz,	thd		1	3	%
	unity gain circuit Pin 2					
Power-supply rejection	f = 50  Hz Pin 2	psrr	65	85		dB
ratio						<u> </u>



Parameters	Test Conditions / Pins	Symbol	Min.	Тур.	Max.	Unit
Clamping comparator						
Typical common-mode	Pin 2	V <sub>cmvr</sub>	0.8		1.6	V
input voltage range						
Maximum distortion	$V_{\text{signal}} = 100 \text{ mV},$	V <sub>dmax</sub>			200	mV
voltage	$R + = R - = 50 \text{ k}\Omega,$					
	C+ = C- = 200  nF,					
	$f_{disto} = 50 \text{ Hz},$					
	$f_{\text{signal}} = 1 \text{ kHz}$ Pin 2					1)
Output voltage	$V_2 > (V_6 + V_7)/2$	V <sub>cout</sub>	0	150	250	mV 1)
	$(10-k\Omega \text{ load to } V_{\text{Ref}})$					
	Pin 5	* 7		* 7		
Output voltage	$V_2 < (V_6 + V_7)/2$	V <sub>cout</sub>		$V_{Ref}$		
	(10-kΩ load to $V_{Ref}$ ) Pin 5					
Wake-up circuit	FIII 3					
-	<b>D</b> ; 0	17		40		4D., 37 2)
Minimum wake-up level	Pin 9	V <sub>in</sub>		40		dBμV <sup>2)</sup>
Internal charging resistor	Pin 3	R <sub>int</sub>		1.5		kΩ
Threshold voltage	Pin 3	V <sub>th</sub>		1.6		V
Output switch current	Pin 10	$I_{SW}$	180	250	550	μΑ
Output switch voltage	Pin 10	$V_{SW}$			5.5	V <sup>3)</sup>
External wake-up resistor	Pins 3 and 13	R <sub>WU</sub>	22			kΩ
External wake-up capacitor	Pins 3 and 13	C <sub>WU</sub>			10	μF
Hold time (± 30%)		t <sub>h</sub>	≈ 1.5	$\times$ R <sub>WU</sub> $\times$	$C_{WU}$	s <sup>4)</sup>
Delay time (± 30%)		t <sub>d</sub>	$\approx c$	$t_{\rm WU} \times 0.75$	kΩ	s <sup>4)</sup>

- 1) IC version with non-inverting comparator available: U4311B
- Measured at Pin 9, referred to 330 Ω
- Protected by a Z-diode, see figure 13
- Valid for 0.1  $\mu$ F  $\leq$  C<sub>WU</sub>  $\leq$  10  $\mu$ F and 22 kΩ  $\leq$  R<sub>WU</sub>  $\leq$  680 kΩ

### **Application**

The U4313B is well-suited to implement UHF remote control or data transmission systems based on a low-current superheterodyne receiver concept. SAW devices may be used in the transmitter's as well as in the receiver local oscillator. The front end should be a discrete circuit application with low-current UHF transistors such as S822T or S852T. The frequency of the local oscillator can be determined either by coaxial resonators or SAW devices. Due to large SAW-resonator tolerance, an IF

bandwidth — and in a FM system additionally the discriminator amplitude characteristic (figure 28) — of 300 kHz or higher is proposed. As the circuit needs only 3.0 V supply voltage for operation, the front end may be a stacked design in order to achieve a total receiver current consumption of approximately 1 mA. Figure 29 shows a principle receiver concept diagram. The application notes ANT012, ANT013 and ANT015 contain more detailed information on complete RF links.



## **Circuit Description**

#### **General functions**

The integrated circuit U4313B includes the following functions: IF amplifier, FM demodulator, wake-up circuit with monoflop, operational amplifier, inverting data comparator and voltage regulator.

The 10.7-MHz IF signal from the front end passes the integrated IF amplifier which operates for amplitude- or frequency-modulated signals to either a logarithmic AM demodulator which was implemented to avoid settling-time problems using an automatic gain control system or a quadrature detector for FM. A data shaping filter — advantageously realized with the internal high-performance operational amplifier — reduces system bandwidth to an optimized compromise regarding transmission distance and data recognition. Thus, an optimal bit-error rate can be achieved without any further active component.

The comparator connected to the output of the filter has a level-dependent hysteresis and clamps its reference voltage to the signal's minimum and maximum peaks as described later.

Without IF-input signal — in normal mode only the IF amplifier and the AM demodulator which operates as a level-strength indicator — are activated. If the level of the IF signal increases, the whole circuitry is turned on by the wake-up circuit. This signal is externally available at

Pin 10 and can be used to wake up a microcontroller. After an adjustable reset time, determined by the monoflop time constant, the integrated circuit returns to sleep mode. In this case, typically 1-mA supply current is required. An external resistor matched at Pin 3 to ground blocks the wake-up circuit and enables complete function at lower IF levels as can be seen in figures 24 and 27, but supply current increases up to typically 2.8 mA.

#### Function of the clamping comparator

The output signal of the operational amplifier is fed to the input of the inverting comparator and two peak detectors (Q1 and Q2, figure 3). Their time constants are distinguished by RC+ and RC-. The component's value must be adapted to the transmission code. The time constant should be large compared to the bit rate for optimized noise and hum suppression. To compensate the input transistors base-emitter-voltage differences, these two signals are buffered by Q3 and Q4. The mean value is used as comparator threshold, the difference of the peak values controls the hysteresis. This clamping comparator operates as a data regenerator.

Another version of the IC, with a non-inverting clamping comparator, is also available (U4311B). Therefore the operational amplifier can be used either as a non-inverting or an inverting filter without the need of any additional components.

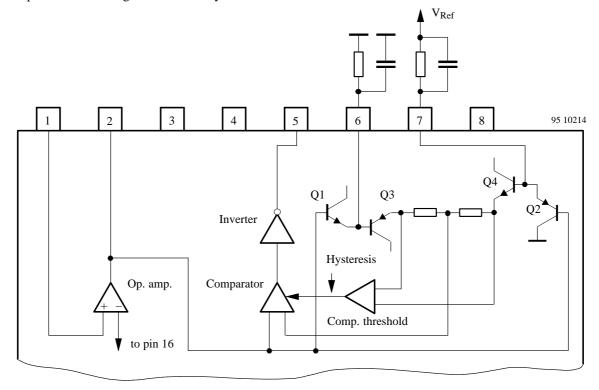


Figure 3. Principle function of the clamping comparator



# **Internal Pin Circuitry**

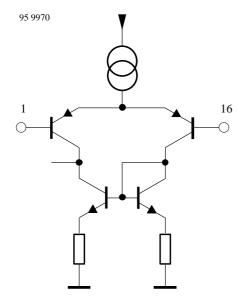


Figure 4. Pin 1 OP<sub>in+</sub>

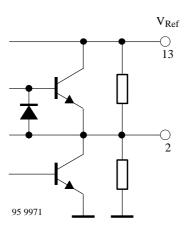


Figure 5. Pin 2 OP<sub>out</sub>

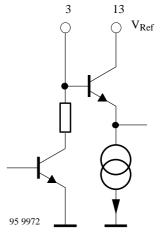


Figure 6. Pin 3 RC<sub>wake</sub>



Figure 7. Pin 4 GND2

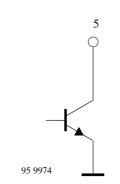


Figure 8. Pin 5 Compout

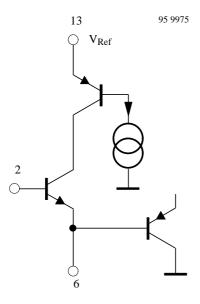


Figure 9. Pin 6 RC-

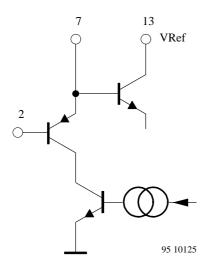


Figure 10. Pin 7 RC+

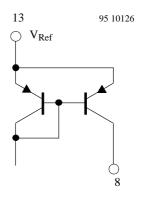


Figure 11. Pin 8 AM<sub>out</sub>

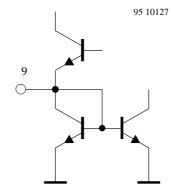


Figure 12. Pin 9 IF<sub>in</sub>

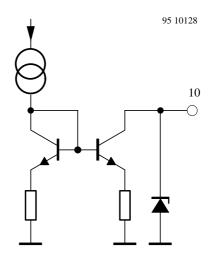


Figure 13. Pin 10 SW<sub>out</sub>



Figure 14. Pin 11 GND1

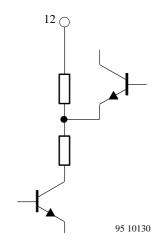


Figure 15. Pin 12 Discr

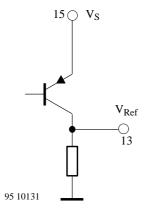


Figure 16. Pin 13  $V_{Ref}$ 

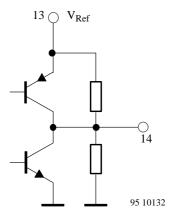


Figure 17. Pin 14 FM<sub>out</sub>

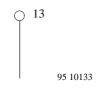


Figure 18. Pin 15  $V_S$ 

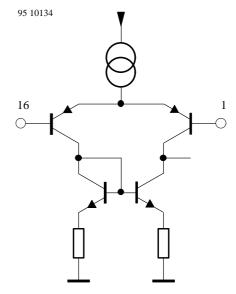


Figure 19. Pin 16 OP<sub>in</sub>-

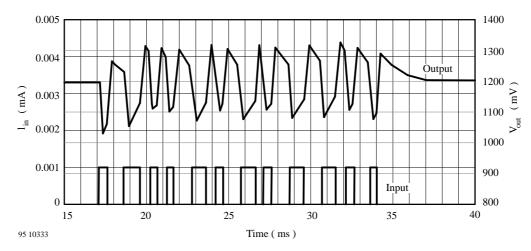


Figure 20. Time domain response of 2-kHz Bessel lowpass data filter

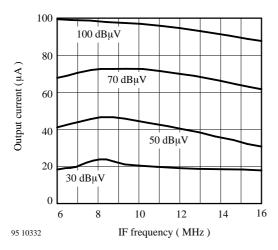


Figure 21. IF-frequency response

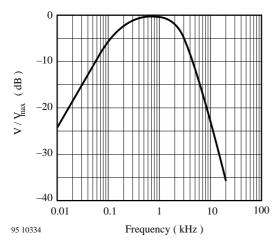


Figure 22. Frequency response of 2-kHz Bessel lowpass data filter

## **Data-Recovering Filter**

The test circuit in figures 23 and 26 includes an example of a data-recovering filter realized with the components  $R_1, R_2, C_1, C_2, C_3$ . It is of a second-order Bessel type with lowpass characteristic, a 3-dB cut-off frequency of 2 kHz and an additional highpass characteristic for suppressing dc and low-frequency ac components. Simulation of time domain and frequency response is drawn in figures 20 and 22. This filter gives a typical application of 1-kBaud Manchester code amplitude-modulated transmission.

The capacitor  $C_2$  is responsible for the highpass cut-off frequency. For a correct pulse response, this highpass cut-off frequency should be as low as possible. Figure 20 shows the transient response and the influence of the dc component. The first pulses might be wrong if the highpass cut-off frequency is too low. For this reason, some burst bits must be transmitted before the real data transmission starts. On the other hand, if the cut-off frequency is too high, roof shaping of the rectangle pulses at the operational amplifier output might causes problems.

The lowpass cut-off frequency and the maximum transimpedance  $V_{out}/I_{in}$  are distinguished by the further external elements. Careful design of the data filter enables optimized transmission range. For designing other filter parameters, refer to filter design handbooks/programs or request TEMIC for support. Some proposals can be found in the application notes ANT012, ANT013 and ANT015.

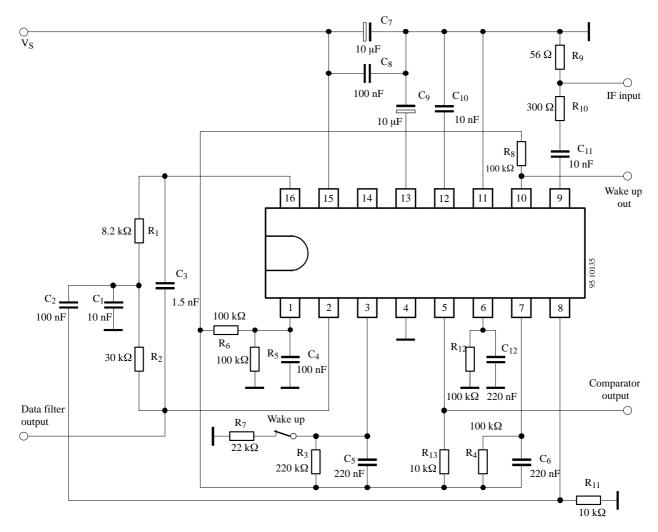


Figure 23. AM test circuit with 2-kHz Bessel lowpass data filter

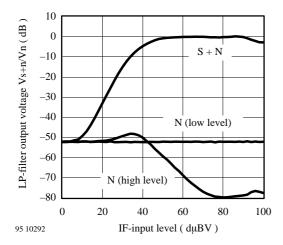


Figure 24. Signal-to-noise ratio AM

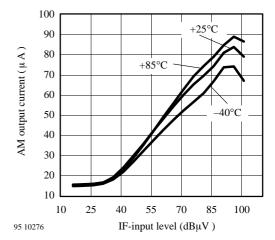


Figure 25. AM-demodulator characteristic vs. temperature

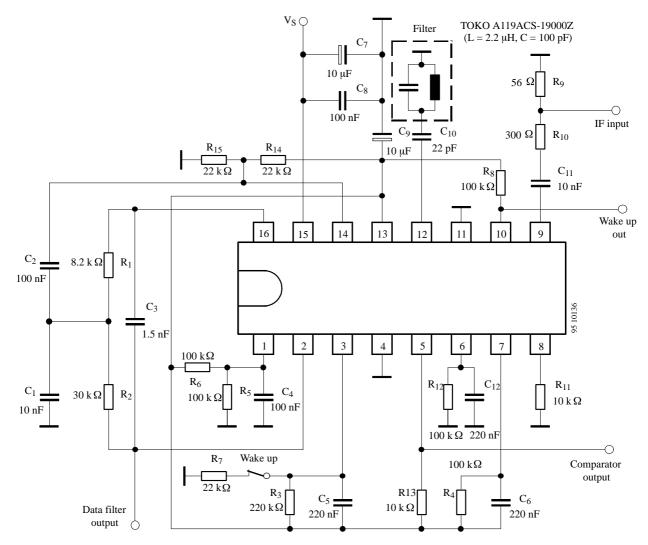
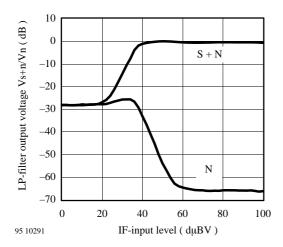
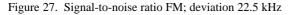


Figure 26. FM test circuit with 2-kHz Bessel low-pass data filter





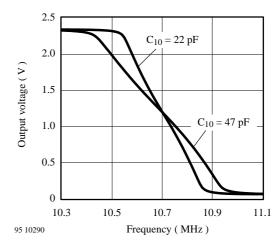


Figure 28. FM-discriminator characteristic



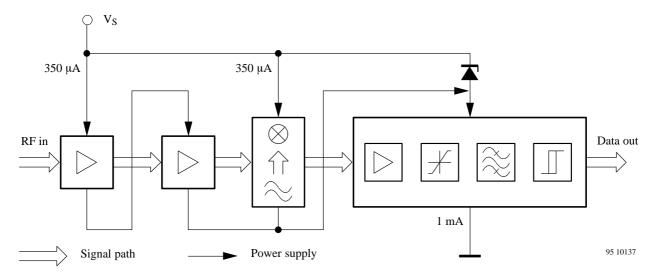


Figure 29. Principle diagram of a UHF remote-control receiver

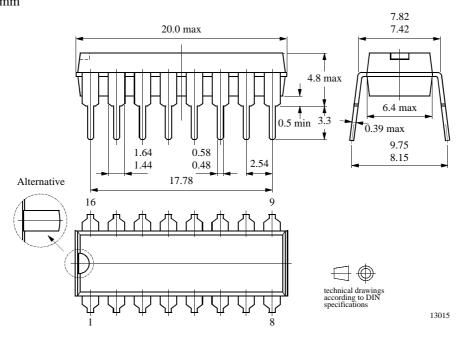
# **Ordering Information**

Extended Type Number	Package	Remarks
U4313B-A	DIP16	
U4313B-AFL	SO16L	



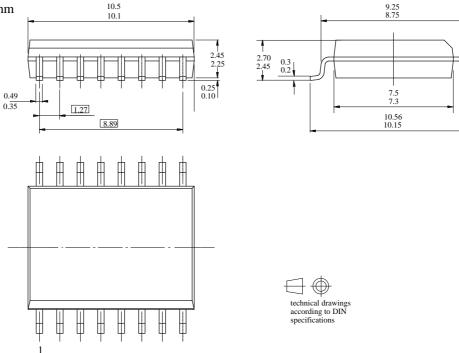
## **Package Information**

## Package DIP16 Dimensions in mm



## Package SO16L

Dimensions in mm



95 11493

**U4313B** 



## **Ozone Depleting Substances Policy Statement**

It is the policy of TEMIC TELEFUNKEN microelectronic GmbH to

- 1. Meet all present and future national and international statutory requirements.
- 2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

**TEMIC TELEFUNKEN microelectronic GmbH** semiconductor division has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

- 1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
- 2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
- 3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

**TEMIC** can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

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